

FEATURES

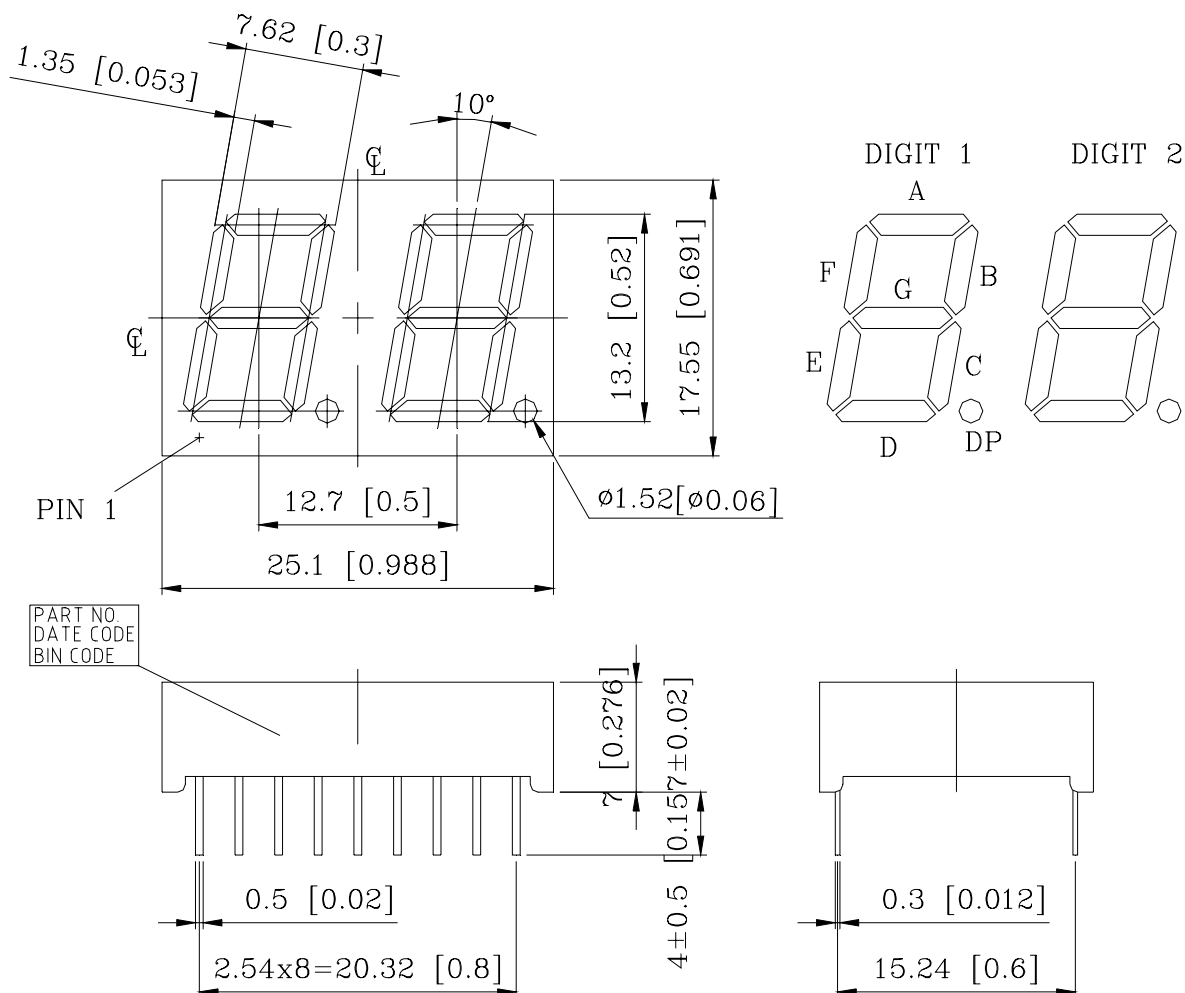
- * 0.52 inch (13.2 mm) DIGIT HEIGHT
- * CONTINUOUS UNIFORM SEGMENTS
- * LOW POWER REQUIREMENT
- * EXCELLENT CHARACTERS APPEARANCE
- * HIGH BRIGHTNESS & HIGH CONTRAST
- * WIDE VIEWING ANGLE
- * SOLID STATE RELIABILITY
- * CATEGORIZED FOR LUMINOUS INTENSITY

DESCRIPTION

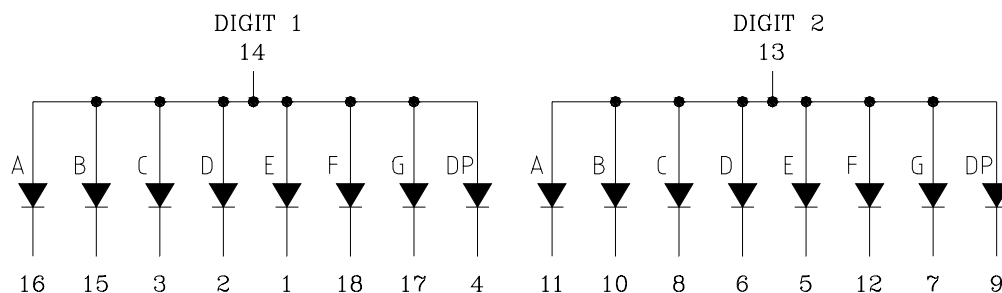
The LTD-5250E-02 is a 0.52 inch (13.2 mm) digit height dual digit seven-segment display. The device uses RED ORANGE LED chips (GaAsP epi on GaP substrate). The display has gray face and white segments.

DEVICE

PART NO.	DESCRIPTION
RED ORANGE	Common anode
LTD-5250E-02	Rt. Hand decimal

PACKAGE DIMENSIONS


NOTES: All dimensions are in millimeters. Tolerances are ± 0.25 mm unless otherwise noted.

INTERNAL CIRCUIT DIAGRAM


PIN CONNECTION

No.	CONNECTION
1	CATHODE E (DIGIT 1)
2	CATHODE D (DIGIT 1)
3	CATHODE C (DIGIT 1)
4	CATHODE DP (DIGIT 1)
5	CATHODE E (DIGIT 2)
6	CATHODE D (DIGIT 2)
7	CATHODE G (DIGIT 2)
8	CATHODE C (DIGIT 2)
9	CATHODE DP (DIGIT 2)
10	CATHODE B (DIGIT 2)
11	CATHODE A (DIGIT 2)
12	CATHODE F (DIGIT 2)
13	COMMON ANODE (DIGIT 2)
14	COMMON ANODE (DIGIT 1)
15	CATHODE B (DIGIT 1)
16	CATHODE A (DIGIT 1)
17	CATHODE G (DIGIT 1)
18	CATHODE F (DIGIT 1)

ABSOLUTE MAXIMUM RATING

PARAMETER	MAXIMUM RATING	UNIT
Power Dissipation Per Segment	75	mW
Peak Forward Current Per Segment (Frequency 1Khz, 10% duty cycle)	100*	mA
Continuous Forward Current Per Segment	25	mA
Forward Current Derating from 25 ⁰ C	0.28	mA/°C
Reverse Voltage Per Segment	8	V
Operating Temperature Range	-35°C to +105°C	
Storage Temperature Range	-35°C to +105°C	
Soldering Conditions : 1/16 inch below seating plane for 3 seconds at 260 ⁰ C		

** see figure 5 to establish pulsed condition*

TRICAL / OPTICAL CHARACTERISTICS AT T_A=25⁰C

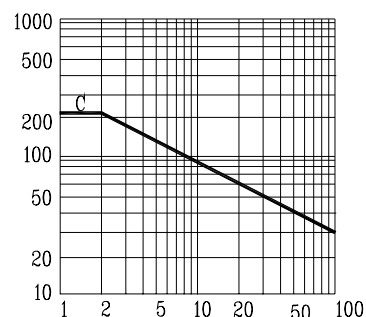
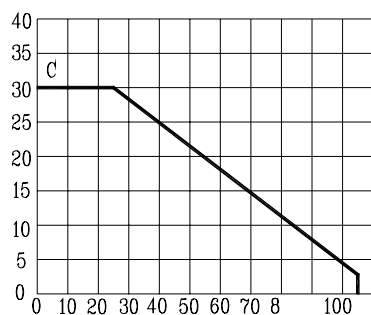
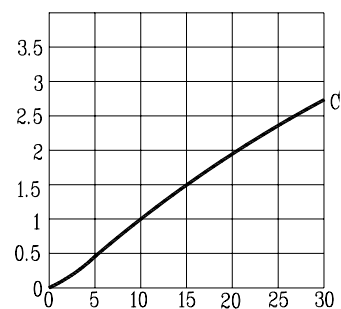
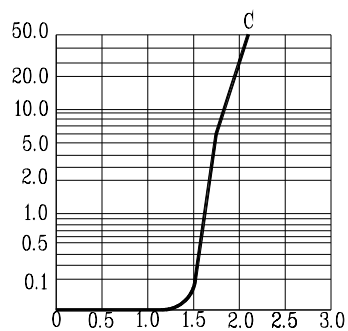
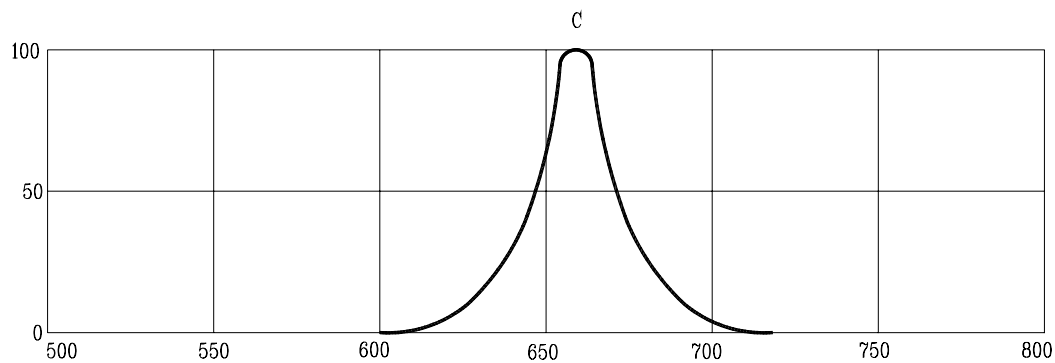
PARAMETER	SYMBOL	MIN.	TYP.	MAX.	UNIT	TEST CONDITION
Average Luminous Intensity Per Segment	I _v	800	2200		μcd	I _F =10mA
Peak Emission Wavelength	λ _p		630		nm	I _F =20mA
Spectral Line Half-Width	Δλ		40		nm	I _F =20mA
Dominant Wavelength	λ _d		621		nm	I _F =20mA
Forward Voltage Per Chip	V _F		2.0	2.6	V	I _F =20mA
Reverse Current Per Chip	I _R			2	μA	V _R =8V
Luminous Intensity Matching Ratio	I _v -m			2:1		I _F =10mA

Note: Luminous intensity is measured with a light sensor and filter combination that approximates the CIE (Commision Internationale De L'Eclairage) eye-response curve.

(V_R =8V, I_R=2uA is based on basic load)

TYPICAL ELECTRICAL / OPTICAL CHARACTERISTIC CURVES

(25°C Ambient Temperature Unless Otherwise Noted)



NOTE: C=AlGaAs RED